HALOGEN

FREE

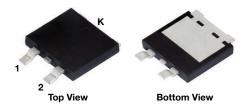


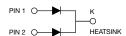
Vishay General Semiconductor

Dual Low-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.30 \text{ V}$ at $I_F = 5.0 \text{ A}$

TMBS® eSMP® Series TO-263AC (SMPD)





PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 15 A			
V _{RRM}	45 V			
I _{FSM}	200 A			
V _F at I _F = 15 A	0.40 V			
T _J max.	150 °C			
Package	TO-263AC (SMPD)			
Diode variations Dual common cathode				

FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 - Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AC (SMPD)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Base P/NHM3_X - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

("_X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V30D45C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	45	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	30	۸	
	per diode		15	А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I _{FSM}	200	А	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	$I_F = 5.0 A$	T _A = 25 °C	V _F ⁽¹⁾	0.42	ı	V	
	$I_F = 7.5 A$			0.44	-		
	I _F = 15 A			0.49	0.57		
	I _F = 5.0 A	T _A = 125 °C		0.30	-		
	I _F = 7.5 A			0.33	-		
	I _F = 15 A			0.40	0.48		
Reverse current per diode	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	1500	μΑ	
		T _A = 125 °C		12	50	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V30D45C	UNIT	
Typical thermal resistance	per diode	- R ₀ JC - R ₀ JA (1)(2)	1.6		
	per device		0.9	°C/W	
	per device		45		

Notes

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

(2) Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V30D45C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel		
V30D45CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		
V30D45CHM3_A/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

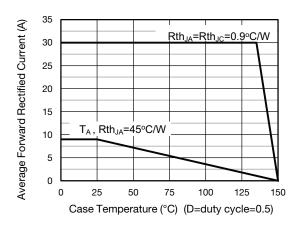


Fig. 1 - Forward Current Derating Curve

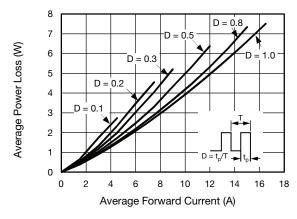


Fig. 2 - Forward Power Loss Characteristics Per Diode

Junction to Ambient

10

100



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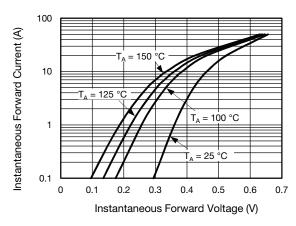
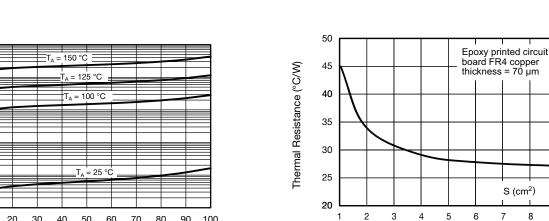


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode



100

10

0.1

0.01

0.1

t - Pulse Duration (s) Fig. 6 - Typical Transient Thermal Impedance Per Diode

Transient Thermal Impedance (°C/W)

Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

Copper Pad Areas (cm²)

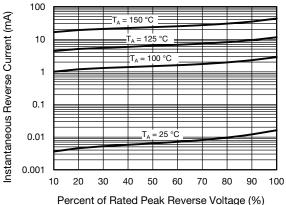


Fig. 4 - Typical Reverse Characteristics Per Diode

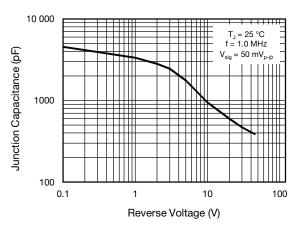


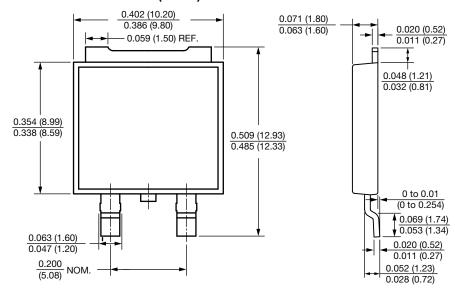
Fig. 5 - Typical Junction Capacitance Per Diode



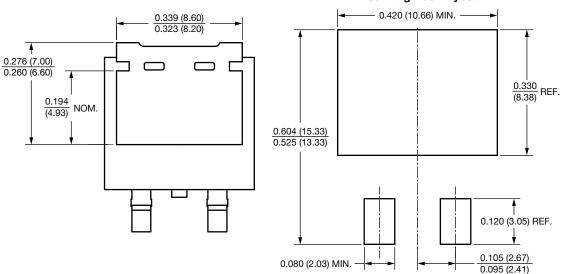
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AC (SMPD)



Mounting Pad Layout





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